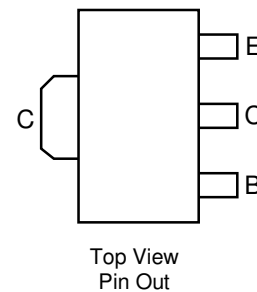
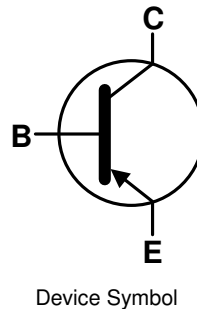


400V PNP HIGH VOLTAGE TRANSISTOR IN SOT89
Features

- $BV_{CEO} > -400V$
- $I_C = -200mA$ High Continuous Current
- $I_{CM} = -500mA$ Peak Pulse Current
- Excellent h_{FE} Characteristics up to $-100mA$
- Low Saturation Voltage $V_{CE(sat)} < -200mV @ -20mA$
- Complementary NPN Type: FCX458
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

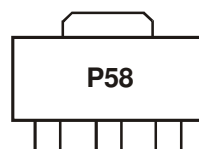
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.05 grams (Approximate)


Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FCX558TA	AEC-Q101	P58	7	12	1,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


P58 = Product Type Marking Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V _{CB0}	-400	V
Collector-Emitter Voltage	V _{CEO}	-400	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-200	mA
Peak Pulse Current	I _{CM}	-500	mA

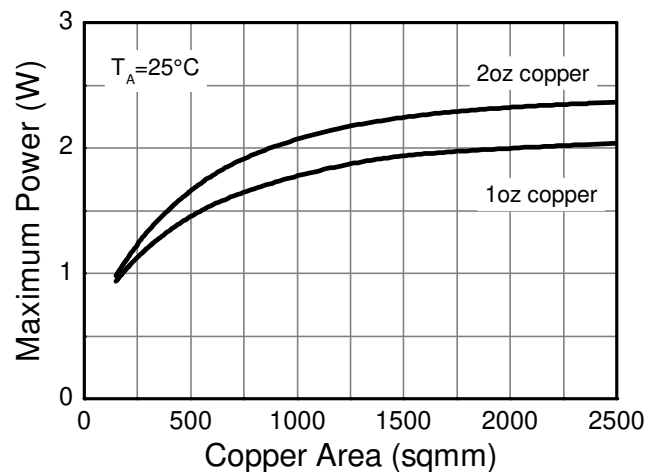
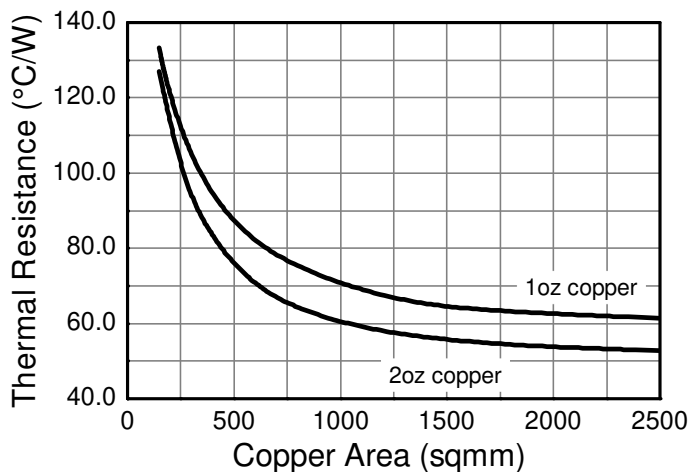
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5)	0.7
		(Note 6)	1
		(Note 7)	1.5
		(Note 8)	2
Thermal Resistance, Junction to Ambient Air	R _{θJA}	(Note 5)	178
		(Note 6)	125
		(Note 7)	83
		(Note 8)	60
Thermal Resistance, Junction to Lead	R _{θJL}	22	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

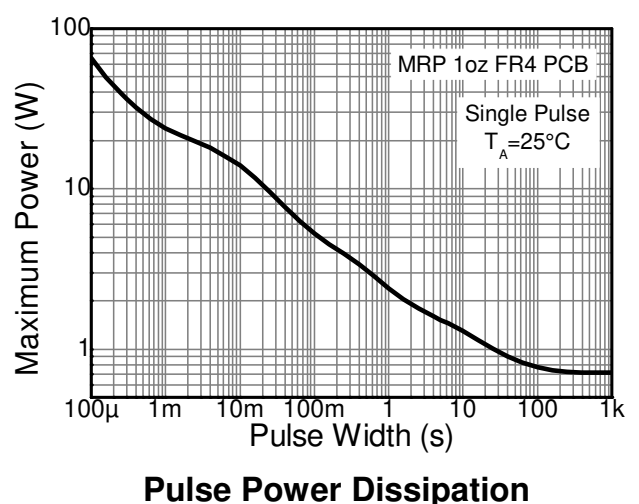
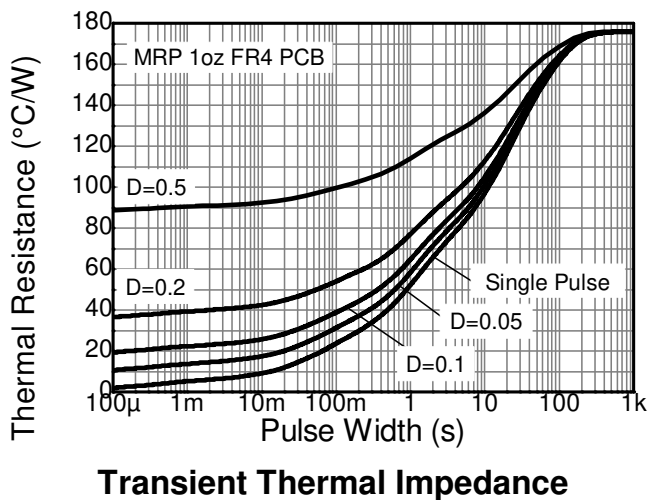
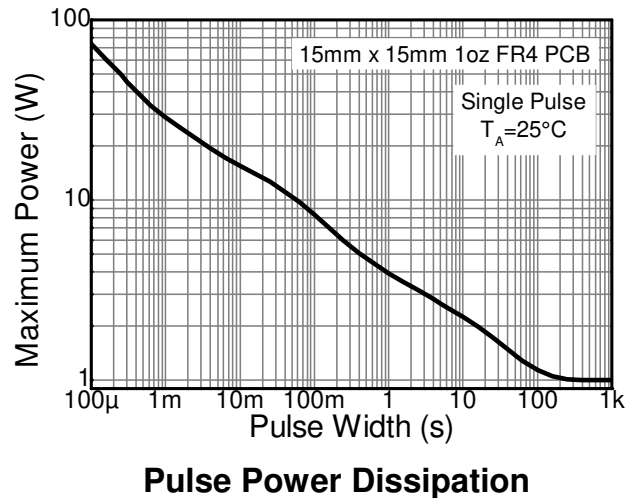
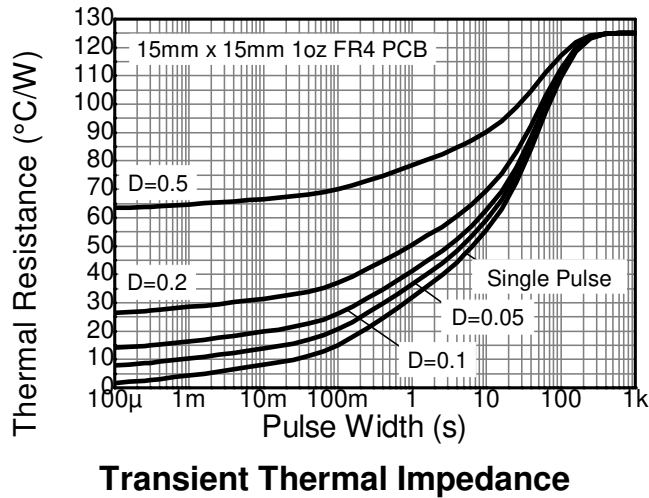
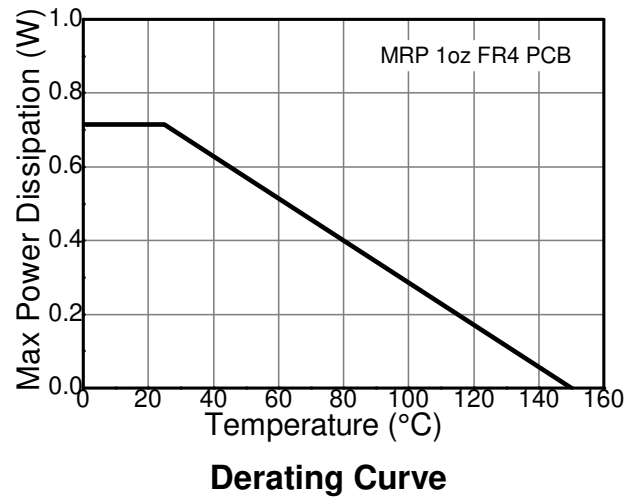
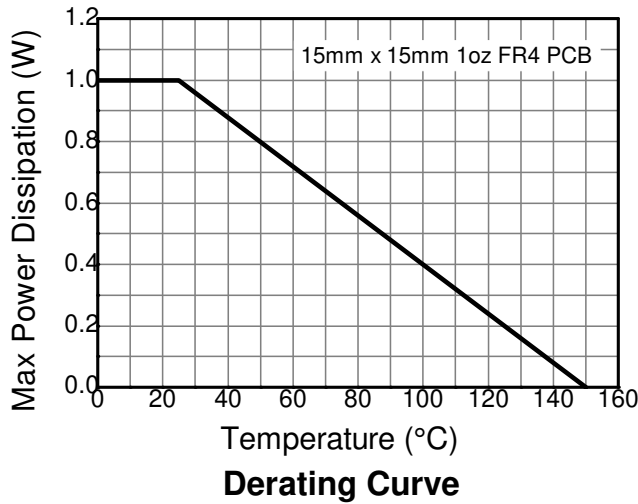
ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the exposed collector pad on minimum recommended pad layout (MRP) 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as Note 5, except the device is mounted with the exposed collector pad on 15mm x 15mm 1oz copper.
 - Same as Note 5, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.
 - Same as Note 5, except the device is mounted with the exposed collector pad on 50mm x 50mm 1oz copper.
 - Thermal resistance from junction to solder-point (on the exposed collector pad).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information


Thermal Characteristics and Derating Information (cont.)

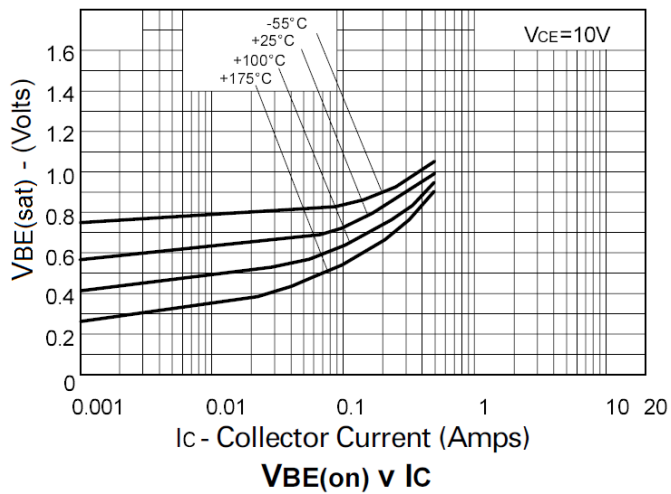
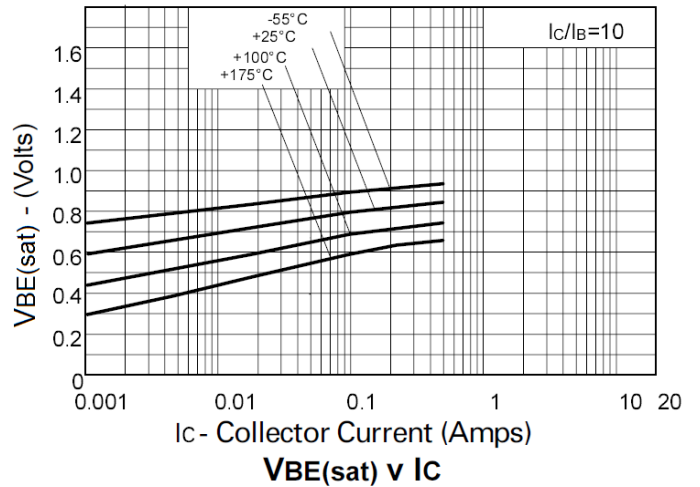
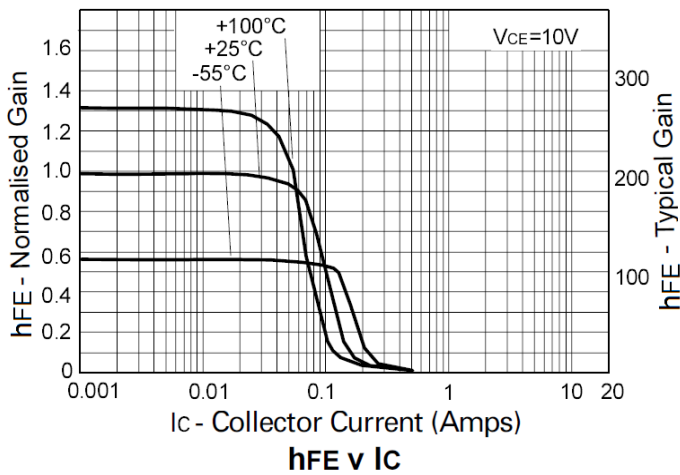
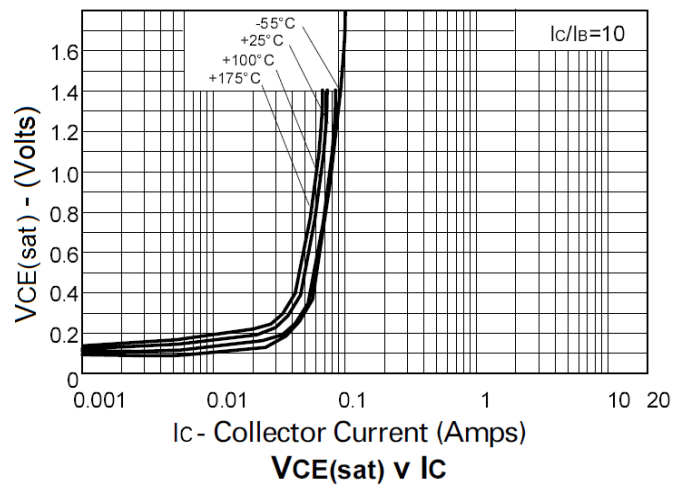
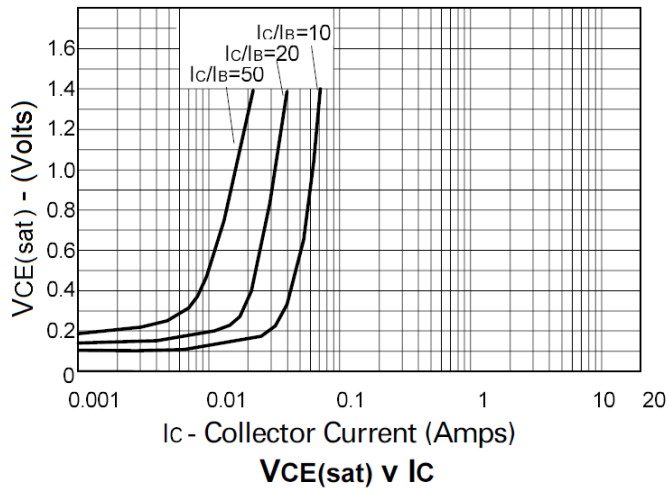


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-400	-540	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-400	-510	-	V	I _C = -1mA
Collector-Emitter Breakdown Voltage	BV _{CES}	-400	-540	-	V	I _C = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	<-1	-100	nA	V _{CB} = -320V
Emitter Cutoff Current	I _{CES}	-	<-1	-100	nA	V _{CE} = -320V
Emitter Cutoff Current	I _{EBO}	-	<-1	-20	nA	V _{EB} = -6V
DC Current Transfer Static Ratio (Note 11)	h _{FE}	100 100 15	- - -	- 300 -	-	I _C = -1mA, V _{CE} = -10V I _C = -50mA, V _{CE} = -10V I _C = -100mA, V _{CE} = -10V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	- -	- -	-0.2 -0.5	V	I _C = -20mA, I _B = -2mA I _C = -50mA, I _B = -6mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	-	-0.9	V	I _C = -50mA, I _B = -5mA
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(on)}	-	-	-0.9	V	I _C = -50mA, V _{CE} = -10V
Transitional Frequency	f _T	50	-	-	MHz	I _E = -10mA, V _{CE} = -20V f = 20MHz
Output Capacitance	C _{obo}	-	-	5	pF	V _{CB} = -20V, f = 1MHz,
Switching Times	t _{on}	-	95	-	nS	I _C = -50mA, V _C = -100V I _{B1} = -5mA, I _{B2} = -10mA
	t _{off}	-	1,600	-		

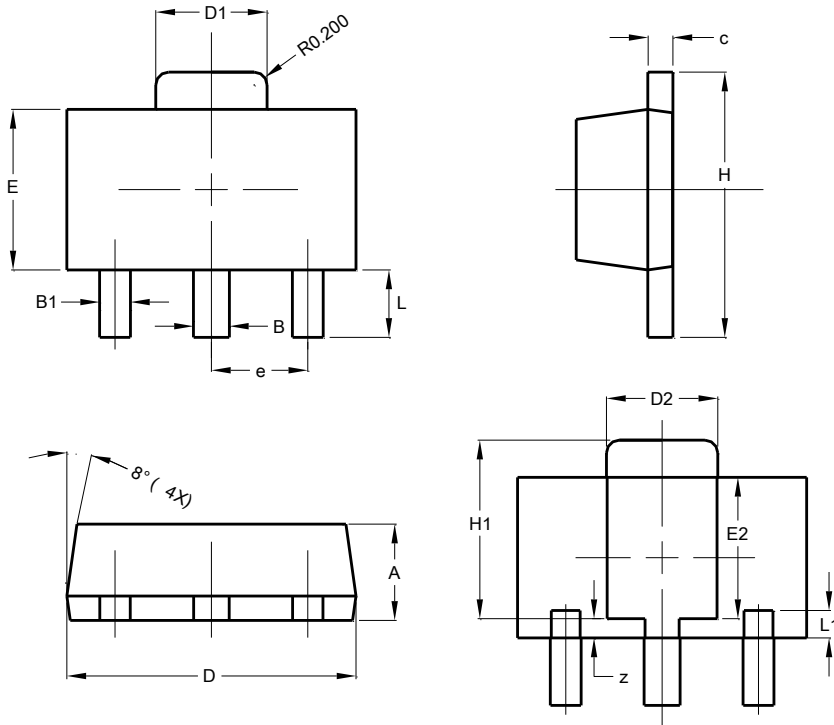
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

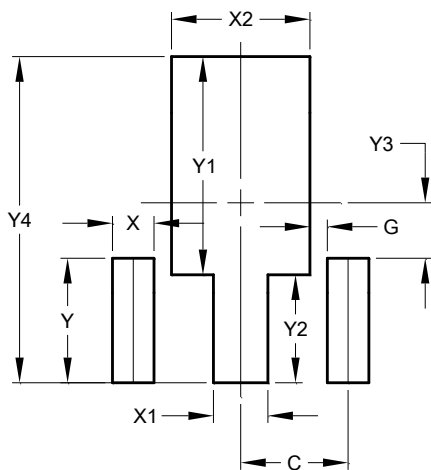
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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